

SI3588DV-T1-GE3

SI3588DV-T1-GE3 Information

		 SI3588DV-T1-GE3 Vishay Siliconix Discrete Semiconductor Products Transistors - FETs, MOSFETs - Arrays MOSFET N/P-CH 20V 2.5A 6-TSOP SOT-23-6 Thin, TSOT-23-6 For the pricing/inventory/lead time, please contact	
	For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



SI3588DV-T1-GE3 Specifications

Manufacturer Part Number	SI3588DV-T1-GE3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Arrays
Package	SOT-23-6 Thin, TSOT-23-6
Series	TrenchFET?
FET Type	N and P-Channel
FET Feature	Logic Level Gate
Drain to Source Voltage (Vdss)	20V
Current - Continuous Drain (Id) @ 25°C	2.5A, 570mA
Rds On (Max) @ Id, Vgs	80 mOhm @ 3A, 4.5V
Vgs(th) (Max) @ Id	450mV @ 250µA (Min)
Gate Charge (Qg) (Max) @ Vgs	7.5nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	-
Power - Max	830mW, 83mW
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	SOT-23-6 Thin, TSOT-23-6
Supplier Device Package	6-TSOP
	Report errors?

SI3588DV-T1-GE3 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

SI3588DV-T1-GE3 Payment Methods



SI3588DV-T1-GE3 Shipping Methods



If you have any question about SI3588DV-T1-GE3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com